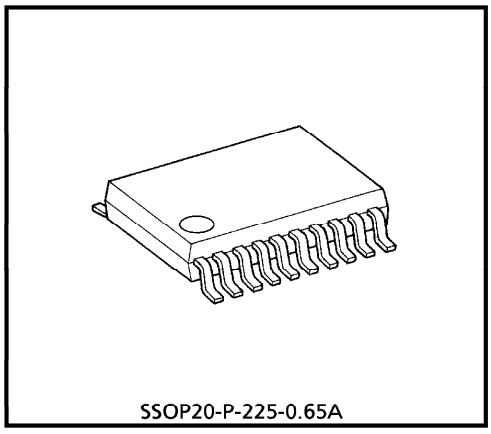
TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

T A 3 1 1 4 5 F N G

FM IF DETECTOR IC FOR PAGER (Built-in 2nd MIX)

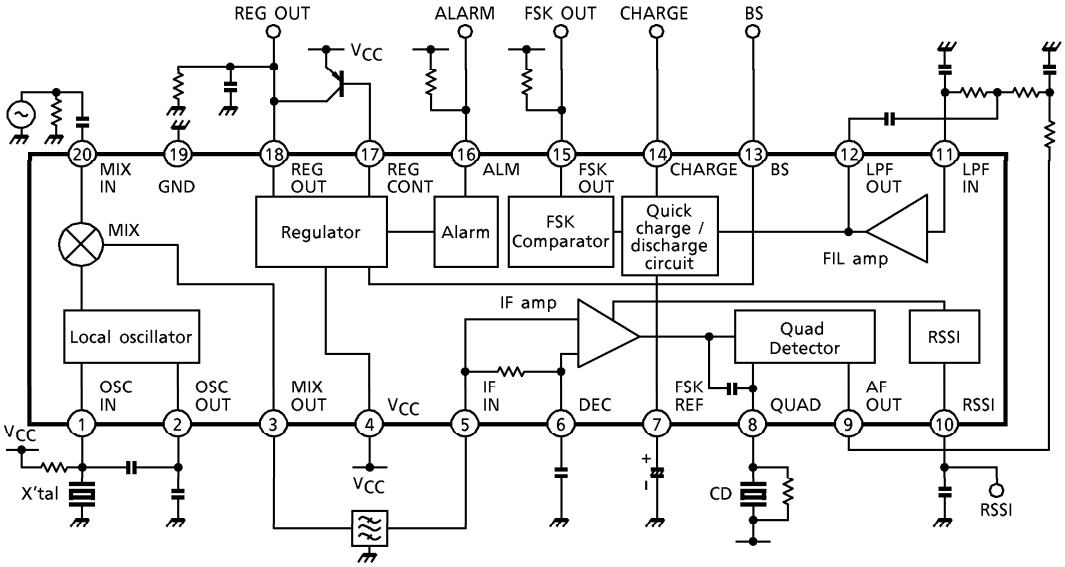


Weight : 0.09g (Typ.)

FEATURES

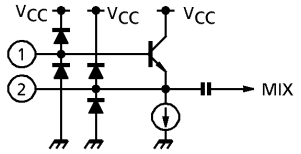
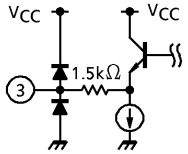
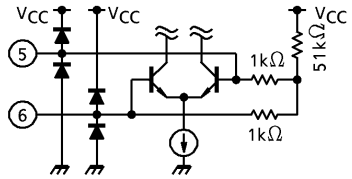
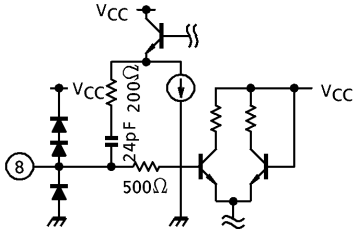
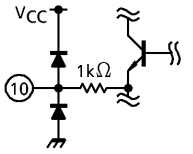
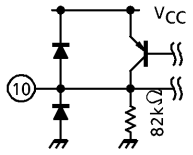
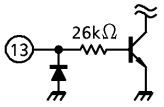
- Built-in RSSI function
  To prevent input overload, RSSI output controls RF attenuator
- Built-in 2nd MIX for double conversion method
  Mix operating frequency: 10~50MHz
- Built-in low pass filter and waveform shaping circuit enable the extraction of FSK signals from voice signal
- High transmit rate : 1200bps (Typ.)
- Built-in battery-saving function
  It is possible to reduce load of the battery which is functioning as power supply
- Battery alarm function (ALM)
  Alarm sensitivity : V_{ALM} = 1.1V (Typ.)
- Constant voltage power supply can be fabricated through externally adding a transistor
  Output voltage : V_{REG} = 1.0V (Typ.)
- Extremely low current consumption : I_{CC} = 1.2mA (Typ.)
- Power supply voltage : V_{CC} = 1.1~3.5V
- Small package : SSOP20PIN (0.65mm pitch)

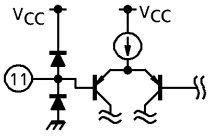
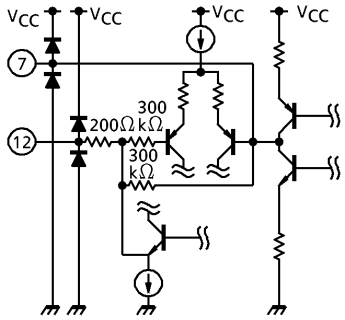
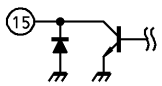
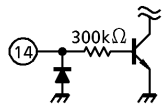
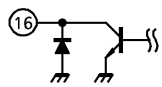
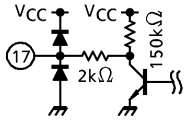
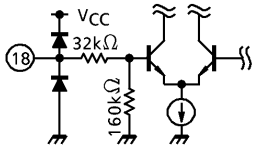
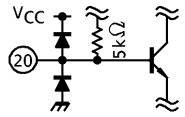
BLOCK DIAGRAM



The TA31145FNG package is Pb-Free.

PIN FUNCTION

PIN No.	PIN NAME	FUNCTION	INTERNAL EQUIPMENT CIRCUIT (RESISTOR AND CAPACITOR ARE TYP. VALUES.)
1	OSC IN	Local oscillator input terminal. In case of oscillating by X'tal, connect to this terminal.	
2	OSC OUT	Local oscillator output terminal. In case of input from external circuit, input to this terminal.	
3	MIX OUT	Mixer output terminal. Output impedance is 2kΩ (Typ.).	
4	V_{CC}	Power supply terminal.	—
5	IF IN	IF amp input terminal (pin 5) and bias decoupling terminal (pin 6). Input impedance is 2kΩ (Typ.).	
6	DEC		
8	QUAD	Phase-shift input terminal for FM demodulator. Connect to the discriminator.	
9	AF OUT	Output terminal for FM demodulator.	
10	RSSI	RSSI output terminal.	
13	BS	Battery-saving control terminal. "H" Battery-saving OFF state "L" Battery-saving state	

PIN No.	PIN NAME	FUNCTION	INTERNAL EQUIPMENT CIRCUIT (RESISTOR AND CAPACITOR ARE TYP. VALUES.)
11	LPF IN	LPF input terminal. Bias is supplied from pin 9 through external resistor.	
12	LPF OUT	LPF output terminal. This output is composed by operation amplifier.	
7	FSK REF	Reference input terminal of differential amplifier which is waveform shaping section. Connect a capacitor externally. By the quick charge / discharge circuit of push-pull output, potentials of pin 7 and pin 12 can be made equal.	
15	FSK OUT	Output terminal for waveform shaping. FSK signal, which is input from LPF OUT (pin 12) and of which waveform is shaped, is output as inverted signal. Connect a pull-up resistor, because it is open collector output.	
14	CHARGE	Control terminal for quick charge / discharge circuit. "H" Quick charge / discharge ON "L" Quick charge / discharge OFF	
16	ALM	Output terminal for ALARM. At $V_{CC} \simeq 1.1V$, this terminal output becomes "H" ($\simeq V_{CC}$) and can indicate deterioration of battery. Connect pull-up resistor, because it is open-collector output.	
17	REG CONT	External transistor for terminal for regulator of external power supply. Connect the PNP transistor externally.	
18	REG OUT	Output voltage monitoring terminal for regulator of external power supply.	
19	GND	GND Terminal.	—
20	MIX IN	Input terminal for MIX. section. Input impedance is 5kΩ (Typ.).	

FUNCTIONS

1. Battery-saving function

   Since the battery-saving function is built-in, this IC can minimize the consumption of battery by means of reducing the current consumption by the battery-saving function when the battery is used as the power supply of the set.
   As the BS terminal (pin 13) is base of the NPN transistor, its input impedance is high and it can be driven with low power. Therefore, this function can be directly driven by CMOS output of microcomputer.

BS TERMINAL (PIN 13) STATE	BATTERY-SAVING FUNCTION	OTHER INTERNAL CIRCUIT OPERATION STATES	QUIESCENT CURRENT CONSUMPTION OF IC
L	Battery-saving ON	Operation stop	0μA (Typ.)
H	Battery-saving OFF	Normal operation	1.2mA (Typ.)

2. Waveform shaping circuit

   The FM detected signal is converted into digital signal by the waveform shaping circuit (configured with comparator). Thus, accurate signal digitization can be achieved when this IC is in a weak electric field or there is noise in the FSK signal. Therefore reading errors of the microcomputer are reduced.
   The waveform shaping circuit of this IC uses the time constant of the capacitor connected to the FSK REF terminal (pin 7) and the internal resistance to integrate the FM detected signal. The resulting voltage is used as the reference (threshold) voltage to shape the waveform and output the waveform-shaped signal from the FSK OUT terminal (pin 15)

3. Quick charge / discharge circuit

   When operation state turn to the battery-saving OFF state (Normal operation state) from the battery-saving state, if the FSK signal is input, the time that the FSK REF terminal (pin 7) arrives at the reference voltage is delayed by the time constant determined by the capacitor connected to the FSK REF terminal (pin 7) and the internal resistance.
   In this case, sometimes the erroneous waveform-shaping signal is output because of the error of the input voltage of the waveform shaping circuit (comparator).
   In such a case, by means of charging or discharging quickly the capacitor connected to the FSK REF terminal (pin 7) by the quick charge / discharge circuit, the time that the FSK REF terminal (pin 7) becomes the same potential as that of the LPF OUT terminal (pin 12) is shortened, and the FSK output of the erroneous waveform shaping signal is prevented.

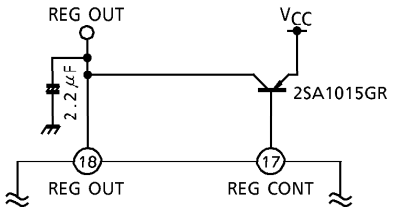
   * When CHARGE terminal (pin 14) is at "H", the quick charge / discharge circuit becomes active state.

4. Alarm function

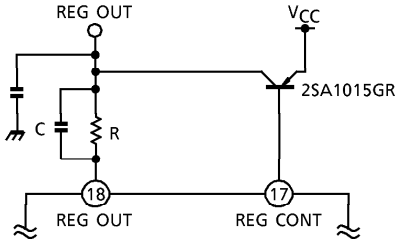
   In case the battery is used as the power supply of the set, when the power supply voltage is reduced and the voltage of the V_{CC} terminal (pin 4) becomes approximately. 1.1V, the output of the ALM terminal (pin 16) rises up to approximately. 1.1V ($\simeq V_{CC}$) and the consumption of the battery power can be detected.

5. Constant voltage regulator for power supply of external part

As shown in the following diagram, connecting the PNP transistor to the REG CONT terminal (pin 17) allows the REG OUT terminal (pin 18) to be used for high-output constant voltage : V_{REG} = 1.0V (Typ.). During battery-saving, the constant voltage output is OFF.

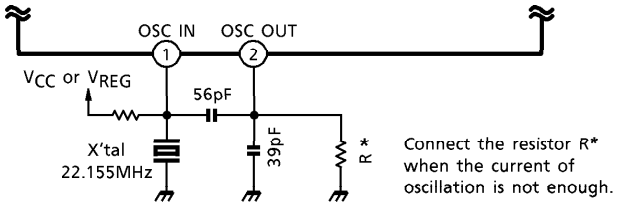


When connecting an external resistor "R" to the REG OUT terminal (pin 18) to raise the output voltage, oscillation may occur in the regulator output. To avoid this, connect a capacitor "C" as shown in the following diagram.



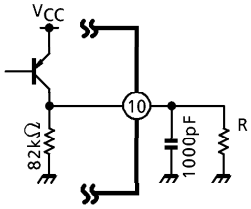
6. Local oscillation circuit

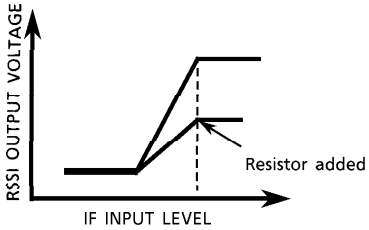
Local oscillation circuit is Colpitts type oscillator composed by internal emitter follower circuit and external X'tal. Connect as shown in the figure below.
Connect a base bias resister between pin 1 and V_{CC} or REG OUT terminal (pin 18).
In case of need to increase the current of local oscillation circuit in order to compose the overtone oscillation and improve the stability of oscillation, connect a resistor between pin 2 and GND. In such a case we recommend connecting a base bias resister between pin 1 and pin 18, or the external regulator (is under the control of the battery-saving). (If a base bias resister is connected between pin 1 and V_{CC}, the current flows across a resistor connected between pin 2 and GND during battery saving.)



7. RSSI function

The RSSI terminal (pin10) outputs a DC potential corresponding to the IF IN terminal (pin5) input level. As the RSSI output is converted into voltage by an internal resistance (82kΩ), its characteristics can be changed as shown in the following diagram. In this case, note that owing to displacement of temperature coefficient between external resistance and internal resistance, the temperature characteristics of the RSSI output may change. Because of the internal circuit structure, do not connect the RSSI terminal (pin10) directly to GND.





MAXIMUM RATINGS (Ta = 25°C)

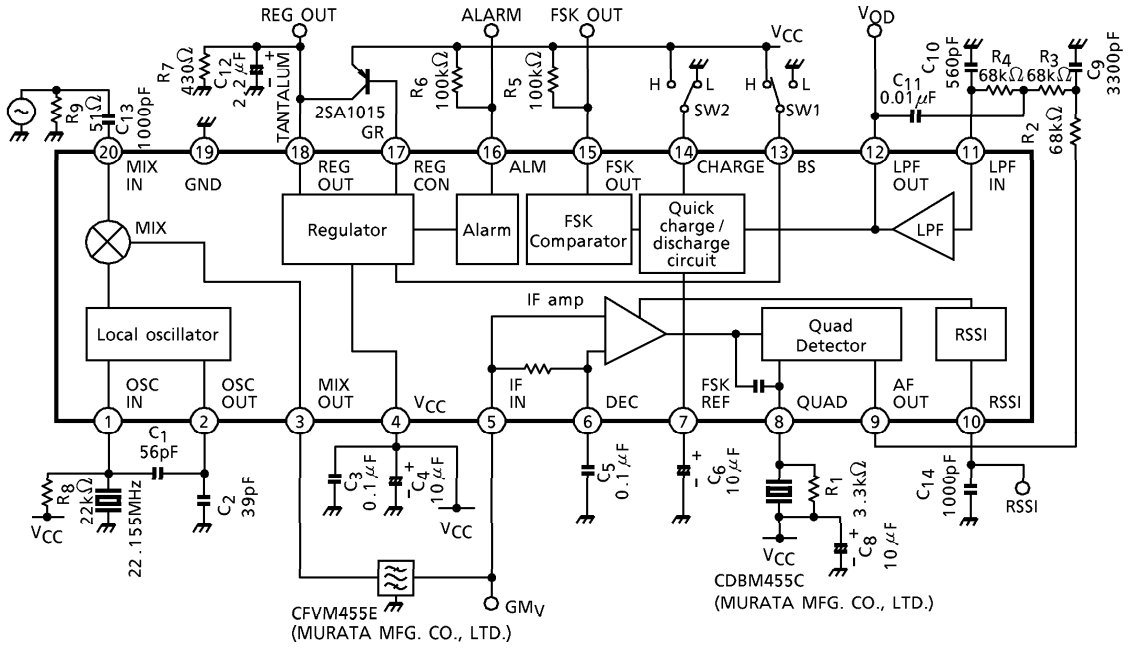
CHARACTERISTIC	SYMBOL	RATING	UNIT
Power Supply Voltage	V_{CC}	4	V
Power Dissipation	P_D	710	mW
Operating Temperature	T_{opr}	− 30~85	°C
Storage Temperature	T_{stg}	− 55~150	°C

ELECTRICAL CHARACTERISTICS

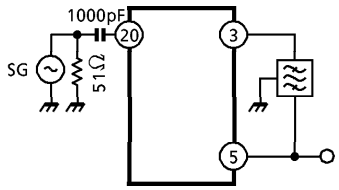
(Ta = 25°C Unless otherwise specified, V_{CC} = 1.4V, $f_{in\ (MIX)}$ = 21.7MHz, $f_{in\ (IF)}$ = 455kHz, Dev = ± 4kHz, f_m = 600Hz)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Voltage Range	V_{CC}	—	—	1.1	1.4	3.5	V
Quiescent Current Consumption	I_{CCQ}	2	—	—	1.2	1.7	mA
Current Consumption at BS	I_{CCO}	3	—	—	0	5	μA
Mixer Conversion Gain	GM_V	1 (1)	Measured through ceramic filter	9	12.5	16	dB
Mixer Intercept Point	I_P	—	—	—	97	—	dBμV
Mixer Input Resistance	R (MIX) IN	—	—	—	5	—	kΩ
Mixer Output Resistance	R (MIX) OUT	—	—	—	2	—	kΩ
IF AMP Input Resistance	R (IF) IN	—	—	—	2	—	kΩ
SN Ratio 1	S / N 1	1 (3)	MIX IN, $V_{IN\ (MIX)}$ = 60dBμV EMF	—	63	—	dB
SN Ratio 2	S / N 2	1 (2)	IF IN, $V_{IN\ (IF)}$ = 60dBμV EMF	—	63	—	dB
SN Ratio 3	S / N 3	1 (2)	IF IN, $V_{IN\ (IF)}$ = 25dBμV EMF	—	35	—	dB
Limiting Sensitivity 1	$V_{I\ (LIM)\ 1}$	1 (3)	MIX IN	—	14	—	dBμV EMF
Limiting Sensitivity 2	$V_{I\ (LIM)\ 2}$	1 (2)	IF IN	—	23	27	dBμV EMF
Demodulated Output Level	V_{OD}	1 (2)	$V_{IN\ (IF)}$ = 60dBμV EMF	30	45	65	mV_{rms}
AM Rejection Ratio	AMR	1 (2)	$V_{IN\ (IF)}$ = 60dBμV EMF, AM = 30%	—	50	—	dB
FSK Output Duty Ratio	DR	1 (4)	$V_{IN\ (IF)}$ = 60dBμV EMF	40	50	60	%
Alarm Detected Voltage	V_{ALM}	1 (5)	—	1.05	1.1	1.15	V
"L" Level Output Voltage (ALM)	$V_{ALM\ L}$	1 (6)	I = 100μA	—	—	0.4	V
"H" Level Leak Current (ALM)	I_{ALM}	1 (7)	—	—	—	2	μA
"L" Level Output Voltage (FSK)	$V_{FSK\ L}$	1 (8)	I = 100μA	—	—	0.4	V
"H" Level Leak Current (FSK)	I_{FSK}	1 (9)	—	—	—	2	μA
Constant Voltage Output	V_{REG}	1 (10)	R_L = 430Ω	0.95	1.0	1.05	V
RSSI Output Voltage	VRSSI	1 (12)	$V_{IN\ (IF)}$ = 65dBμV EMF	0.45	0.6	0.80	V
RSSI Output Resistance	RRSSI	—	—	—	82	—	kΩ
Quick Charge / Discharge Current	I_{CH}	4	V_7 = 0V, V_{12} = 0.18V	35	70	110	μA
"L" Level Output Voltage (REG CONT)	REG L	1 (11)	I = 100μA	—	—	0.6	V

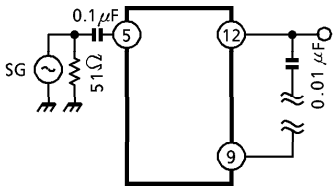
TEST CIRCUIT 1



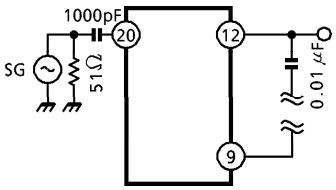
(1) GM_V



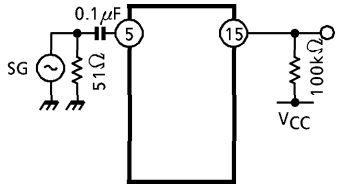
(2) SN2, SN3, $V_{I\,(LIM)\,2}$, V_{OD}, AMR



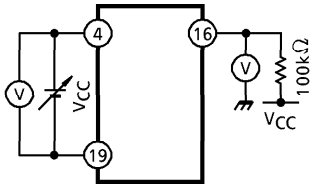
(3) SN1, $V_{I\,(LIM)\,1}$



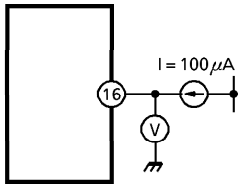
(4) D_R



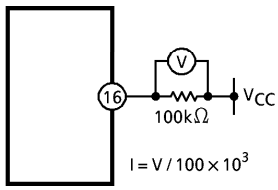
(5) V_{ALM}



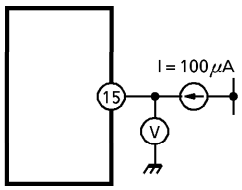
(6) $V_{ALM\ L}$



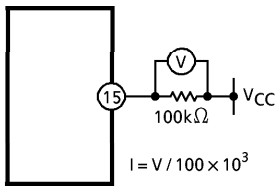
(7) I_{ALM}



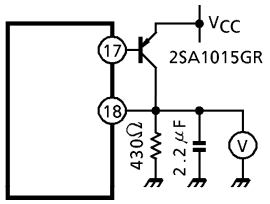
(8) V_{FSK} L



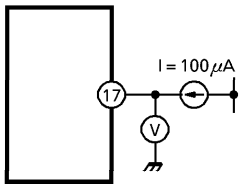
(9) I_{FSK}



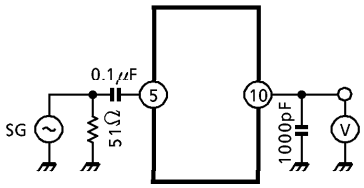
(10) V_{REG}



(11) R_{EG} L



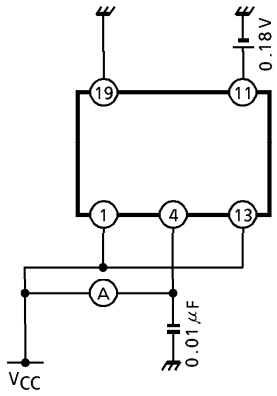
(12) V_{RSSI}



Test condition ····· TEST CIRCUIT 1.

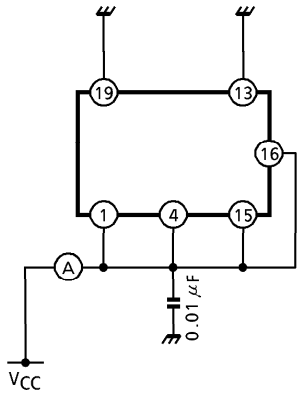
TEST CIRCUIT 2

I_{CCQ}



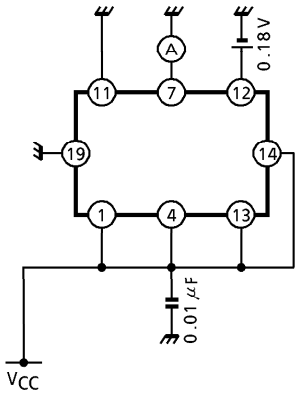
TEST CIRCUIT 3

I_{CCO}

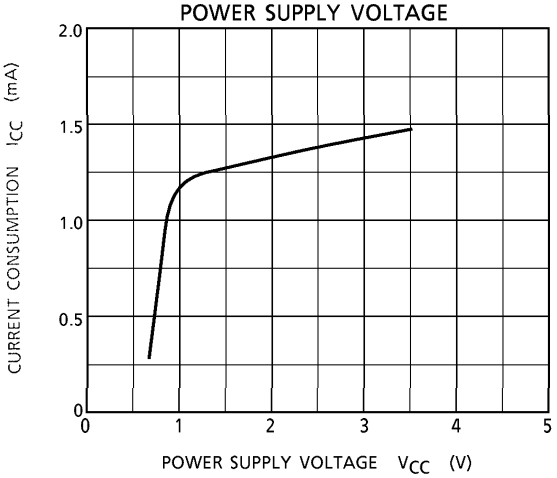


TEST CIRCUIT 4

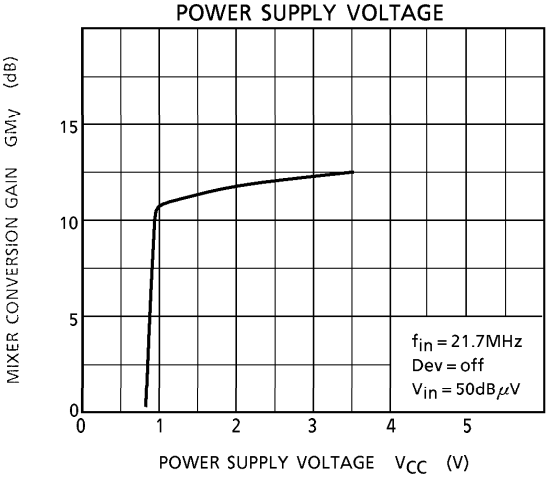
I_{CH}



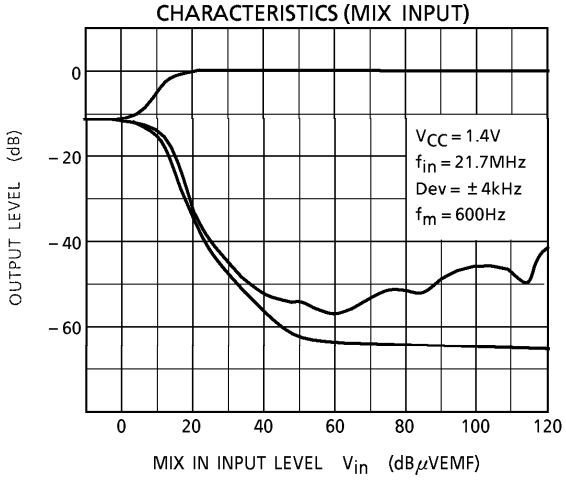
CURRENT CONSUMPTION – POWER SUPPLY VOLTAGE



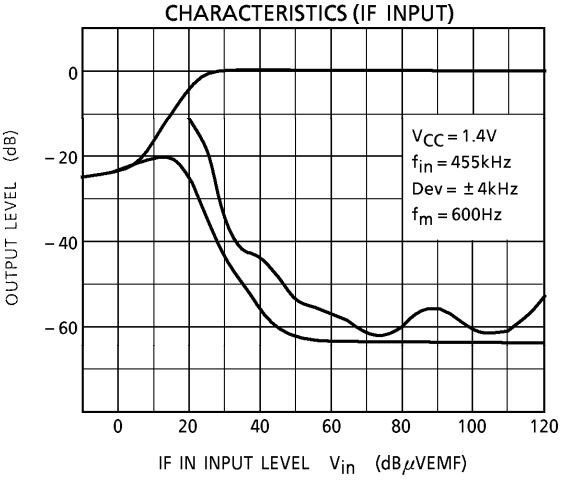
MIXER CONVERSION GAIN – POWER SUPPLY VOLTAGE



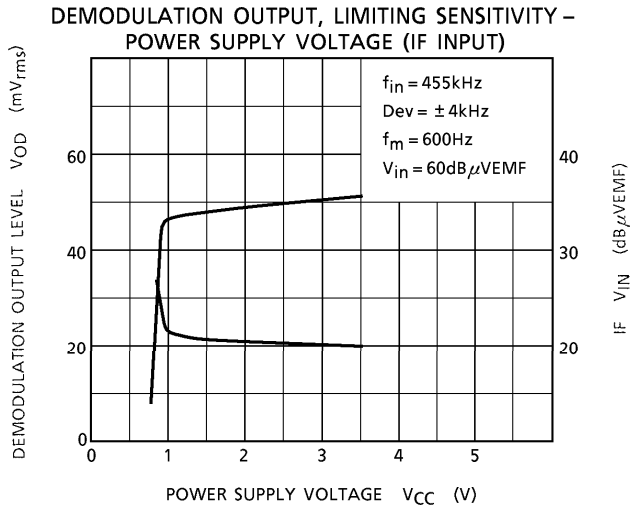
S / N, AMR INPUT / OUTPUT CHARACTERISTICS (MIX INPUT)



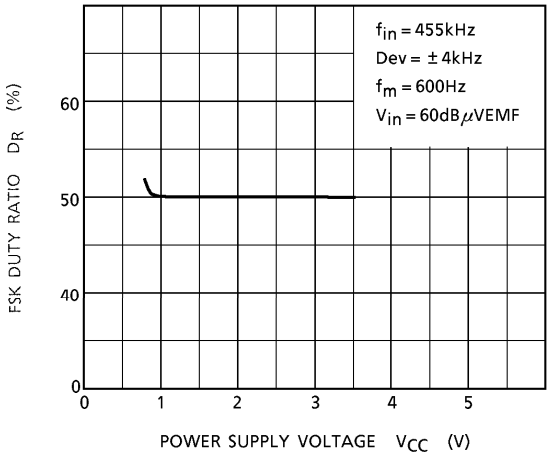
S / N, AMR INPUT / OUTPUT CHARACTERISTICS (IF INPUT)



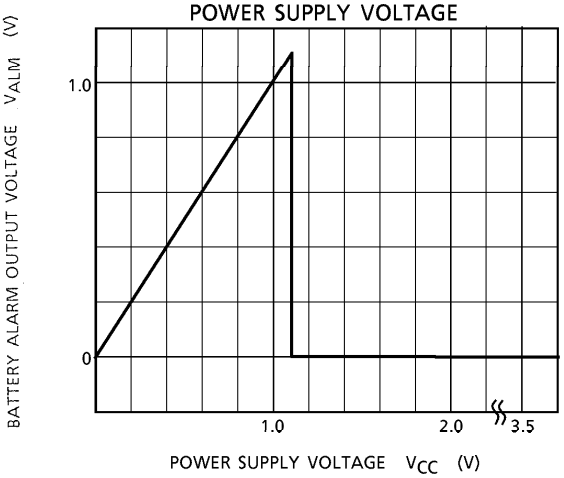
DEMODULATION OUTPUT, LIMITING SENSITIVITY – POWER SUPPLY VOLTAGE (IF INPUT)



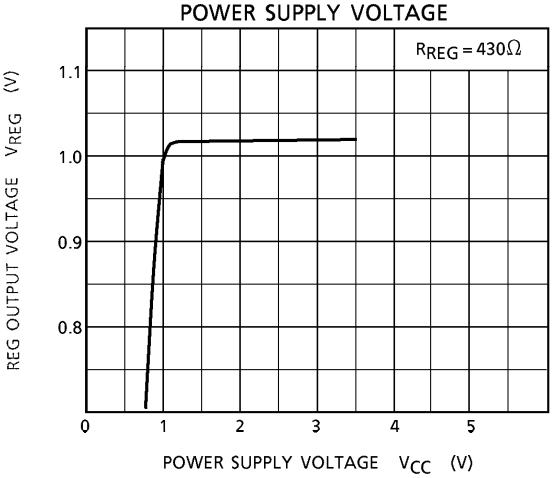
FSK DUTY RATIO – POWER SUPPLY VOLTAGE



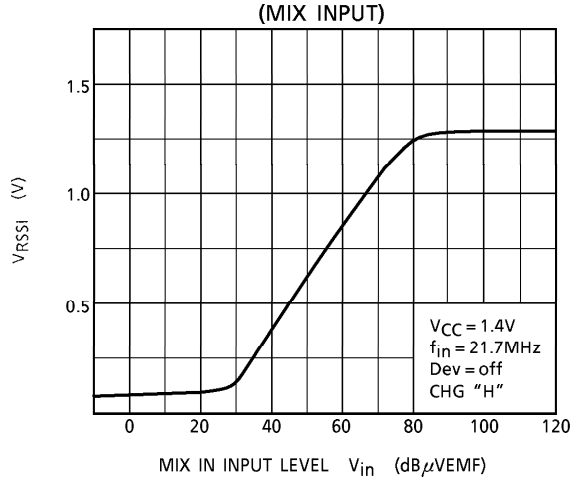
BATTERY ALARM OUTPUT VOLTAGE – POWER SUPPLY VOLTAGE



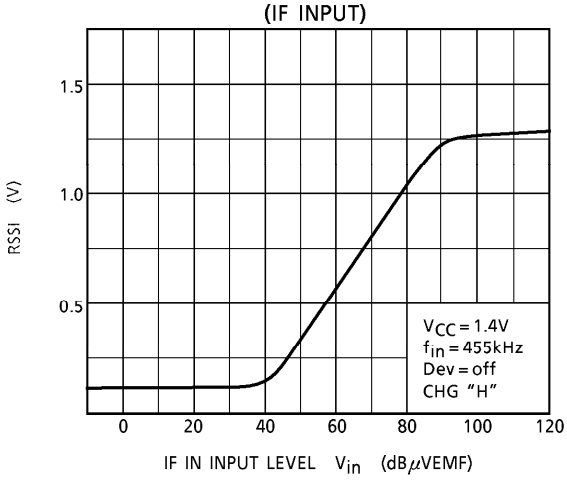
REG OUTPUT VOLTAGE – POWER SUPPLY VOLTAGE



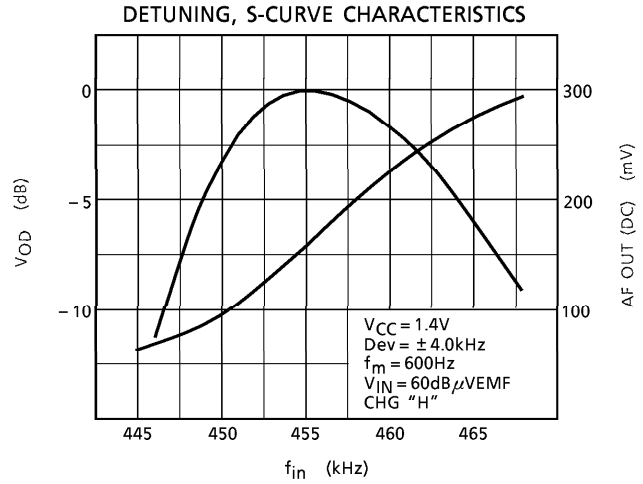
RSSI OUTPUT VOLTAGE CHARACTERISTICS (MIX INPUT)



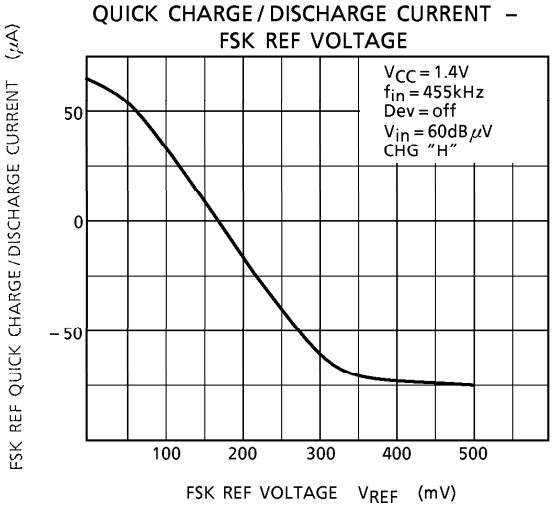
RSSI OUTPUT VOLTAGE CHARACTERISTICS (IF INPUT)



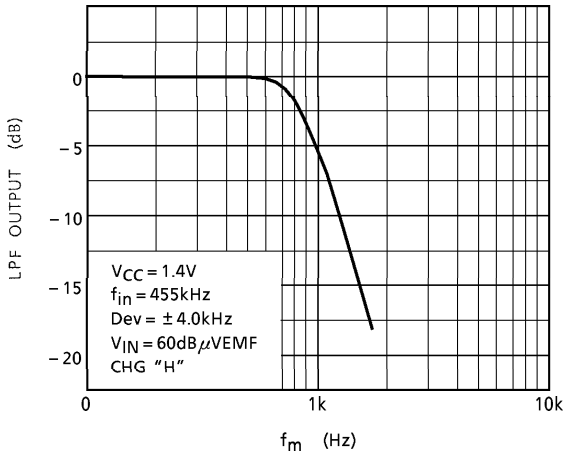
DETUNING, S-CURVE CHARACTERISTICS



QUICK CHARGE / DISCHARGE CURRENT – FSK REF VOLTAGE

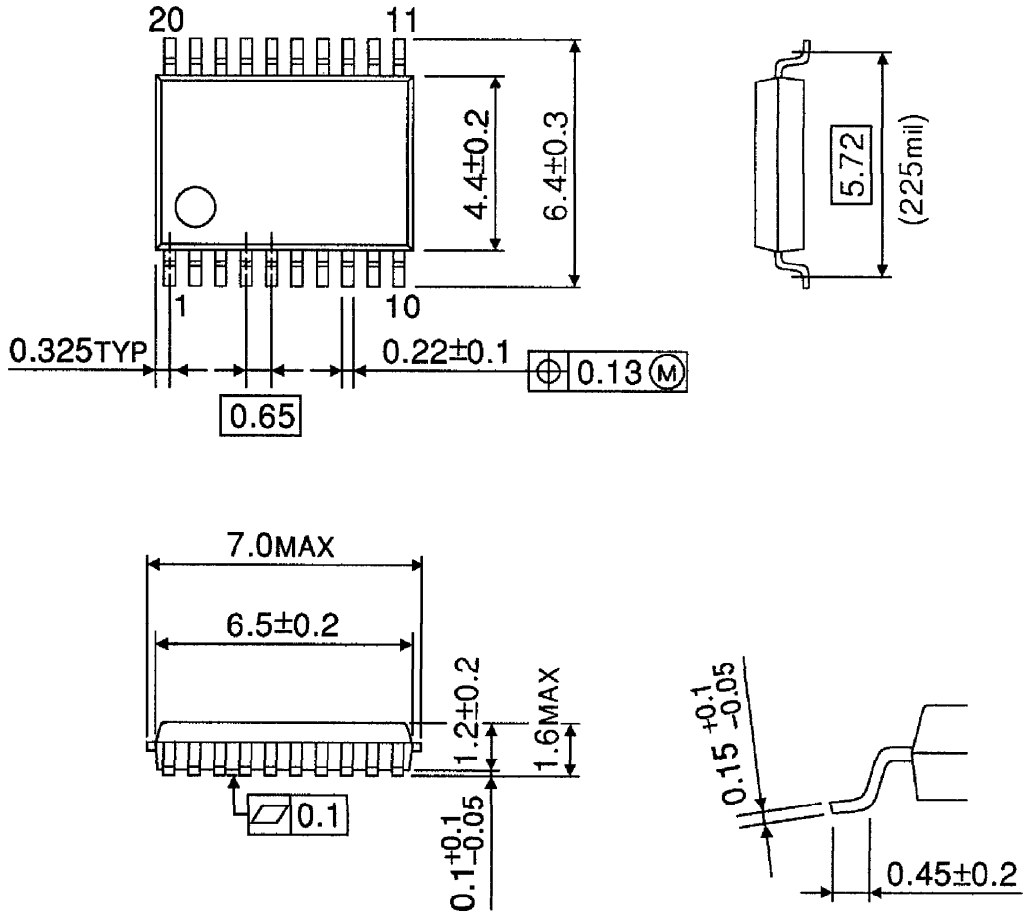


LPF CHARACTERISTICS



PACKAGE DIMENSIONS

SSOP20-P-225-0.65A Unit : mm



Weight : 0.09g (Typ.)

Notice for Pb free product
About solderability, following conditions were confirmed
Solderability
(1) Use of Sn-36Pb solder bath
- solder bath temperature = 230°C
- dipping time = 5seconds
- the number of times = once
- use of R-type flux

(2) Use of Sn-3.0Ag-0.5Cu solder bath
- solder bath temperature = 245°C
- dipping time = 5seconds
- the number of times = once
- use of R-type flux

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000707EBA

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